TOSHIBA Field-Effect Transistor Silicon P-Channel MOS Type (U-MOSVI)

SSM3J130TU

O Power Management Switch Applications

- 1.5 V drive
- Low ON-resistance: $R_{DS(ON)}$ = 63.2 m Ω (max) (@V_{GS} = -1.5 V)
 - $R_{DS(ON)} = 41.1 \text{ m}\Omega \text{ (max)} (@V_{GS} = -1.8 \text{ V})$
 - $R_{DS(ON)} = 31.0 \text{ m}\Omega \text{ (max)} (@V_{GS} = -2.5 \text{ V})$

 $R_{DS(ON)}$ = 25.8 m Ω (max) (@V_{GS} = -4.5 V)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-Source voltage		V _{DSS}	-20	V	
Gate-Source voltage		V _{GSS}	± 8	V	
Drain current	DC	I _D	-4.4	А	
	Pulse	I _{DP}	-8.8	~	
Power dissipation		P _D (Note 1)	800	mW	
		P _D (Note 2)	500	11100	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

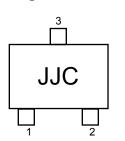
Note 1: Mounted on a ceramic board.

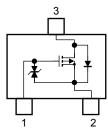
(25.4 mm \times 25.4 mm \times 0.8 mm, Cu Pad: 645 mm²) Note 2: Mounted on an FR4 board.

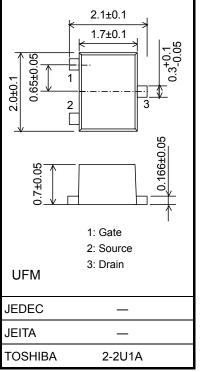
 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{Cu Pad: 645 mm}^2)$

Marking

Equivalent Circuit (top view)







Weight: 6.6 mg (typ.)

Unit: mm

Electrical Characteristics (Ta = 25°C)

Chara	cteristic	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain Source breakdown voltage	V (BR) DSS	I _D = -1 mA, V _{GS} = 0 V		-20			V	
Drain-Source breakdown voltage		V (BR) DSX	I _D = -1 mA, V _{GS} = 5 V	(Note 4)	-15	_		_
Drain cut-off current		I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V		_	_	-1	μA
Gate leakage curr	ent	I _{GSS}	V_{GS} = ±8 V, V_{DS} = 0 V		_		±1	μA
Gate threshold vo	Itage	V _{th}	V _{DS} = -3 V, I _D = -1 mA		-0.3		-1.0	V
Forward transfer a	admittance	Y _{fs}	V_{DS} = -3 V, I _D = -2.0 A	(Note 3)	8.8	17.5		S
Drain–source ON-resistance		I_{D} = -4.0 A, V_{GS} = -4.5 V	(Note 3)	—	20.9	25.8	mΩ	
	R _{DS (ON)}	I _D = -4.0 A, V _{GS} = -2.5 V	(Note 3)	_	24.2	31.0		
		I _D = -2.5 A, V _{GS} = -1.8 V	(Note 3)	_	28.8	41.1		
		I _D = -1.5 A, V _{GS} = -1.5 V	(Note 3)	_	32.4	63.2		
Input capacitance		C _{iss}			_	1800		
Output capacitance		C _{oss}	V _{DS} = -10 V, V _{GS} = 0 V f = 1 MHz		_	205		pF
Reverse transfer capacitance		C _{rss}			_	190		
Switching time	Turn-on time	t _{on}	V _{DD} = -10 V, I _D = -1.5 A		_	25		ns
	Turn-off time	t _{off}	V_{GS} = 0 to -2.5 V, R_{G} = 4.7 Ω		_	133		
Total Gate Charge		Qg			_	24.8		
Gate-Source Charge		Q _{gs}	V _{DS} = -10 V, I _{DS} = - 4.4 A, V _{GS} = - 4.5 V		_	18.0		nC
Gate-Drain Charge		Q _{gd}	VGS 4.5 V		_	6.8	_	
Drain-Source forward voltage		VDSF	I _D = 4.4 A, V _{GS} = 0 V	(Note 3)	_	0.83	1.2	V

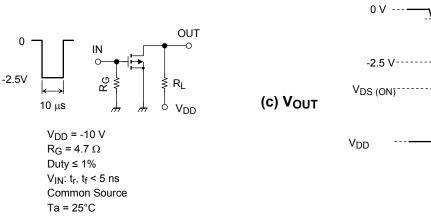
Note3: Pulse test

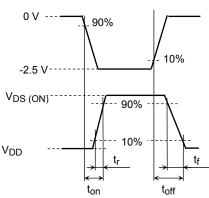
Note4: If a forward bias is applied between gate and source, this device enters V(BR)DSX mode. Note that the drain-source breakdown voltage is lowered in this mode.

Switching Time Test Circuit

(a) Test Circuit







Usage Considerations

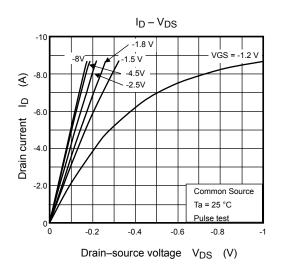
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below –1 mA for the SSM3J130TU. Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

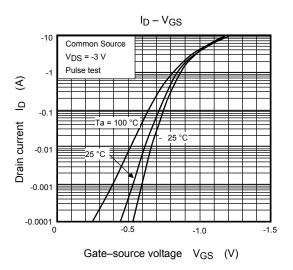
Take this into consideration when using the device.

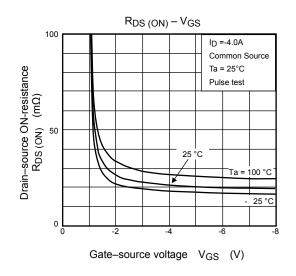
Handling Precaution

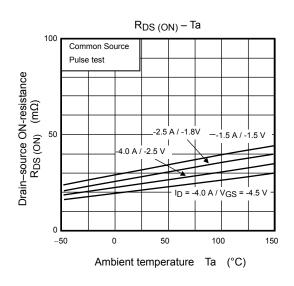
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

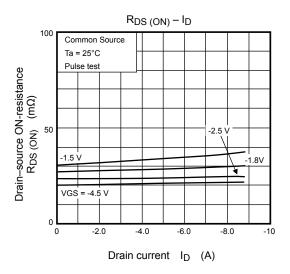
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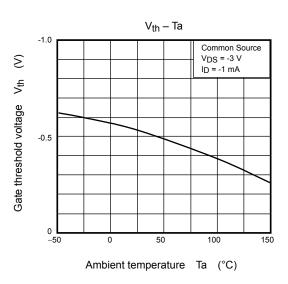




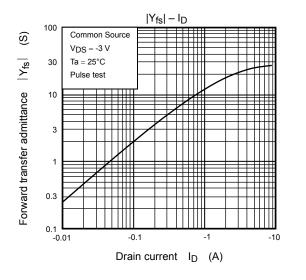


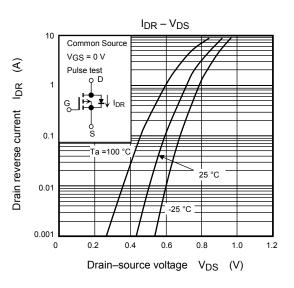


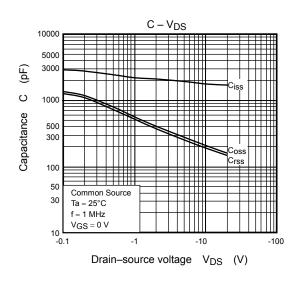


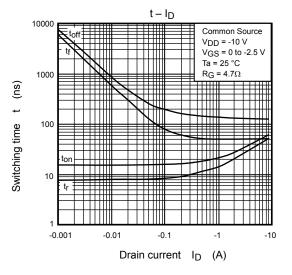


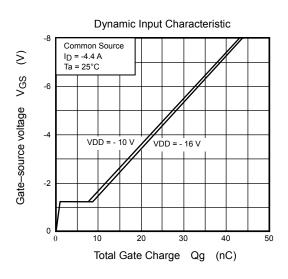
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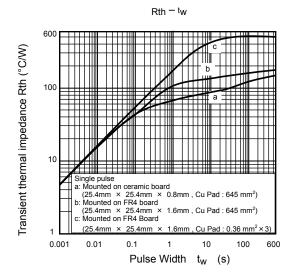




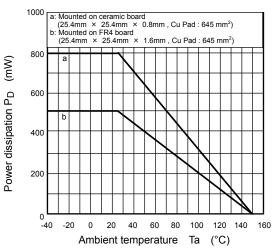


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